NSN 5962-01-351-6209

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View Online at https://aerobasegroup.com/nsn/5962-01-351-6209

Body Length:
0.540 inches
Body Width:
Between 0.245 inches and 0.300 inches
Body Height:
Between 0.045 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5895-01-299-3419
Features Provided:
Burn in and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
9 input
Case Outline Source And Designator:
F-9 mil-m-38510
Current Rating Per Characteristic:
50.00 milliamperes forward current, peak total value not applicable
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, parallel fifo
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
First-in first-out
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
20 flat leads
Shelf Life:

N/a

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Demilitarization:

No

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